



GPDP4189

AVALANCHE RECTIFIER DIODE

VOLTAGE UP TO	3200 - 3800 V
AVERAGE CURRENT	1890 A
SURGE CURRENT	21 kA

BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
V _{RRM}	Repetitive peak reverse voltage	3200 - 3800 V
V _{RSM}	Non-repetitive peak reverse voltage	V
I _{RRM}	Repetitive peak reverse current, max.	V _{RRM} , single phase, half wave, T _{jmax}
P _{RSM}	Peak reverse power, max	T _{jmax} , tp = 20μs

FORWARD CHARACTERISTICS

I _{F(AV)}	Average forward current	Sine wave, 180° conduction, T _h = 55°C	1890 A
I _{F(RMS)}	R.M.S. forward current	Sine wave, 180° conduction, T _h = 55°C	2967 A
I _{FSM}	Surge forward current	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _{jmax}	21 kA
I ² t	I ² t for fusing coordination		2205 kA ² s
V _{F(TO)}	Threshold voltage	T _j = T _{jmax}	1.03 V
r _F	Forward slope resistance	T _j = T _{jmax}	0.320 mΩ
V _{FM}	Peak forward voltage, max	Forward current I _F = 4000 A, T _j = 25°C	2.00 V

SWITCHING CHARACTERISTICS

Q _{rr}	Reverse recovery charge, typ	T _j = T _{jmax} , I _F = 2000 A, di/dt = -5 A/μs	μC
I _{rr}	Reverse recovery current	V _R = 100 V	A
t _{rr}	Reverse recovery time		μs
V _{FP}	Forward recovery voltage	T _j = T _{jmax} , di/dt = A/μs	V

THERMAL AND MECHANICAL CHARACTERISTICS

R _{th(j-c)}	Thermal resistance (junction to case)	Double side cooled	0.020 °C/W
R _{th(c-h)}	Thermal resistance (case to heatsink)	Double side cooled	0.002 °C/W
T _{jmax}	Max operating junction temperature		160 °C
T _{stg}	Storage temperature		-40 / 160 °C
F	Clamping force ± 10%		22 kN
	Mass		500 g